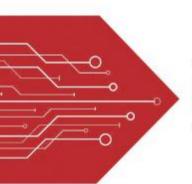
# MSKSEMI















**ESD** 

TVS

TSS

MOV

**GDT** 

**PLED** 

Product data sheet





**SMB** 

### **FEATURES**

- . Plastic package has underwrites laboratory flammability Classification  $94\,\mathrm{V}\text{-}0$
- . Low profile surface mount package
- . Built-in strain relief
- Fast switching for high efficiency
- . Glass Passivated chip junction
- . High temperature soldering:

250C/10 second at terminals

#### **MECHANICAL DATA**

- Case: JEDED DO-214AA molded plastic over glass passivated chip
- . Terminals: Solder plated, Solderable per MIL-STD-750, method 2026
- . Polarity: Color band denotes cathode end Weight: 0.002ounce, 0.064 gram

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

### **MAXIMUM RATINGS & THERMAL CHARACTERISTICS**

PARAMETELS	SYMBOLS	RS2A	RS2B	RS2D	RS2G	RS2J	RS2K	RS2M	UNIT
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	Volts
	$I_{F(AV)}$	2.0				Amps			
Peak Forward Surge Current $8.3  ms$ single half sine wave superimposed on rated load (JEDEC method) $T_L = 100  C$	$I_{FSM}$	I <sub>FSM</sub> 50				Amps			
Typical Thermal Resistance (NOTE 1)	$R_{\theta JA} = R_{\theta JL}$	10			c/ <b>W</b>				
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to + 150				С			

## **ELECTRICAL CHARACTERISTICS**

PARAMETELS		SYMBOLS	RS2A	RS2B	RS2D	RS2G	RS2J	RS2K	RS2M	UNIT
Maximum Instantaneous Forward Voltage at 2.0 A		$V_{F}$	1.30						Volts	
Maximum DC Reverse Current at rated DC Blocking Voltage	$T_A = 25 C$ $T_A = 125 C$	$I_R$	5.0 200			μA				
Typical Reverse Recovery Time I <sub>F</sub> =0.5A, I <sub>R</sub> =1.0A, I <sub>R</sub> =0.25A,		$T_{rr}$		1:	50		250	50	00	ns
Typical junction capacitance at 4.0 V, 1 MHz $C_{\rm J}$		$C_{\rm J}$	30				pF			

#### Notes:

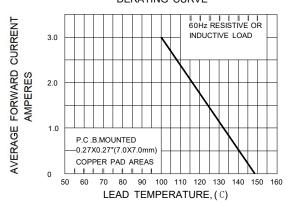
1. Thermal resistance from Junction to ambient and from junction to lead mounted on P.C.B. with  $0.27 \times 0.27$ " ( $7.0 \times 7.0$ mm) copper pad areas.



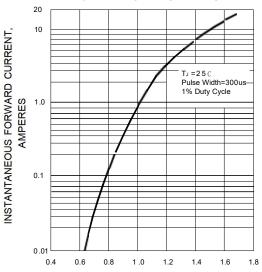
F1G.2-MAXIMUM NON-REPETITIVE PEAK



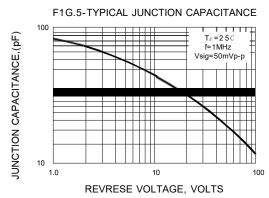
F1G. 1-FORWARD CURRENT DERATING CURVE



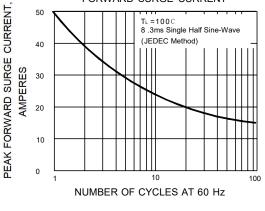
F1G.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



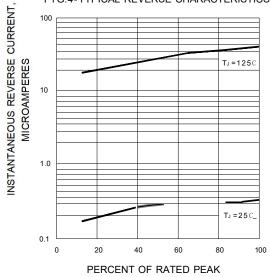
INSTANTANEOUS FORWARD VOLTAGE, VOLTS



FORWARD SURGE CURRENT 50 TL = 100C 8 .3ms Single Half Sine-Wave (JEDEC Method) 40 30



F1G.4-TYPICAL REVERSE CHARACTERISTICS



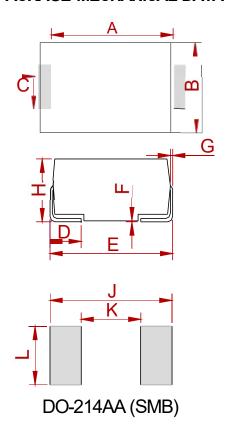
REVERSE VOLTAGE,(%)



## Semiconductor Co

#### · Complance

# PACKAGE MECHANICAL DATA



	Dimensions					
Ref.	Ref. Millimeters		Inches			
	Min.	Max.	Min.	Max.		
Α	4.25	4.75	0.167	0.187		
В	3.30	3.94	0.130	0.155		
С	1.85	2.21	0.073	0.087		
D	0.76	1.52	0.030	0.060		
Е	5.08	5.59	0.200	0.220		
F	0.051	0.203	0.002	800.0		
G	0.15	0.31	0.006	0.012		
Н	2.11	2.44	0.083	0.096		
J	6.80		0.270			
K		2.60		0.100		
L	2.40		0.090			

## **REEL SPECIFICATION**

P/N	PKG	QTY
RS2A THRU RS2M	SMB	3000



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